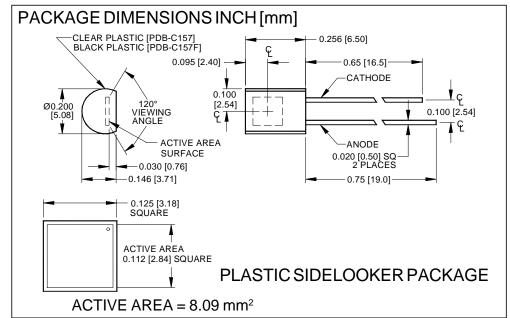
PHOTONIC Silicon Photodiode, Blue Enhanced Photoconductive **DETECTORS INC.** Type PDB-C157, with daylight filter Type PDB-C157F





FEATURES

- Large active area
- Photoconductive
- Low cost
- High speed

DESCRIPTION: The **PDB-C157** detector is a 8.09 mm² planar pin photodiode packaged in a water clear plastic sidelooker housing. Designed for high speed, low capacitance, photoconductive applications. The **PDB-C157F** includes a daylight filter.

APPLICATIONS

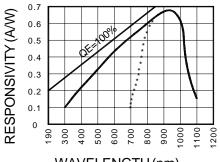
- Smoke detectors
- Bar code
- TV & VCR remotes
- Dimmers

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS	
$V_{\mathtt{BR}}$	Reverse Voltage		50	V	
T _{STG}	Storage Temperature	-40	+100	∘C	
T _o	Operating Temperature Range	-40	+80	∘C	
T _s	Soldering Temperature*		+260	∘C	
IL	Light Current		0.5	mA	

^{*1/16} inch from case for 3 secs max

SPECTRAL RESPONSE



WAVELENGTH (nm)

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I _{sc}	Short Circuit Current	H = 100 fc, 2850 K	85	120		μΑ
I _D	Dark Current	H = 0, V _R = 10 V		2	30	nA
R _{SH}	Shunt Resistance	$H = 0, V_R = 10 \text{ mV}$	100	150		МΩ
TCR _{SH}	RSH Temp. Coefficient	$H = 0, V_R = 10 \text{ mV}$		-8		%/°C
C _J	Junction Capacitance	H = 0, V _R = 10 V*		30	50	pF
λrange	Spectral Application Range	(without daylight filter)**	400		1100	nm
λр	Spectral Response - Peak			950		nm
V_{BR}	Breakdown Voltage	I = 10 μA	30	75		V
NEP	Noise Equivalent Power	V _R = 10 V @ Peak		4.4x10 ⁻¹⁴		W/ √Hz
tr	Response Time	$RL = 1 K\Omega V_R = 50 V$		50		nS